RoHS

COMPLIANT

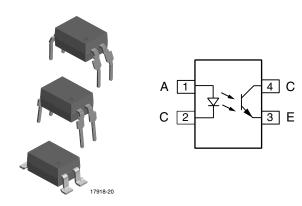
FREE

GREEN (5-2008)



Vishay Semiconductors

Optocoupler, Phototransistor Output, High Reliability, 5000 V_{RMS}, 110 °C Rated



DESCRIPTION

The 110 °C rated SFH1617A (DIP) feature a high current transfer ratio, low coupling capacitance and high isolation voltage. These couplers have a GaAs infrared diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a plastic DIP-4 package.

The coupling devices are designed for signal transmission between two electrically separated circuits.

The couplers are end-stackable with 2.54 mm spacing.

Creepage and clearance distances of > 8.0 mm are achieved with option 6. This version complies with IEC 60950 (DIN VDE 0805) for reinforced insulation up to an operation voltage of $400~V_{RMS}$ or DC. Specifications subject to change.

FEATURES

- Operating temperature from 55 °C to + 110 °C
- Good CTR linearity depending on forward current
- Isolation test voltage, 5000 V_{RMS}
- High collector emitter voltage, V_{CEO} = 70 V
- · Low saturation voltage
- · Fast switching times
- Low CTR degradation
- Temperature stable
- Low coupling capacitance
- End stackable, 0.100" (2.54 mm) spacing
- · High common mode interference immunity
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- AC adapter
- SMPS
- PLC
- · Factory automation
- Game consoles

AGENCY APPROVALS

- UL1577, file no. E52744
- cUL tested to CSA 22.2 bulletin 5A
- DIN EN 60747-5-2 (VDE 0884)/DIN EN 60747-5-5 (pending) available with option 1
- BSI EN 60950; EN 60065
- FIMKO
- CQC (pending)

| ORDERING INFORMATIO | N | | | |
|--------------------------|----------|----------------|------------------------------|------------------------------|
| S F H 1 6 PART NUMB | 1 7 A - | # X 0 | # # T PTION TAPE AND REEL OF | Option 6 10.16 mm 10.16 mm |
| AGENCY CERTIFIED/PACKAGE | | CTF | ₹ (%) | |
| UL, cUL, BSI, FIMKO | 40 to 80 | 63 to 125 | 100 to 200 | 160 to 320 |
| DIP-4 | = | SFH1617A-2 | SFH1617A-3 | - |
| VDE, UL, cUL, BSI, FIMKO | 40 to 80 | 63 to 125 | 100 to 200 | 160 to 320 |
| DIP-4, 400 mil, option 6 | = | - | SFH1617A-3X016 | - |
| SMD-4, option 7 | - | SFH617A-2X017T | - | - |

Note

· Additional options may be possible, please contact sales office

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| ABSOLUTE MAXIMUM RATIN | NGS (T _{amb} = 25 °C, unless o | therwise specifie | ed) | |
|--|--|-------------------|--------------------|-----------|
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT |
| INPUT | | | | |
| Reverse voltage | | V _R | 6.0 | V |
| DC forward current | | I _F | 60 | mA |
| Surge forward current | t ≤ 10 μs | I _{FSM} | 2.5 | Α |
| LED power dissipation | | P _{diss} | 70 | mW |
| OUTPUT | | | | |
| Collector emitter voltage | | V _{CEO} | 70 | V |
| Emitter collector voltage | | V _{ECO} | 7.0 | V |
| Collector current | | I _C | 50 | mA |
| Collector peak current | $t_p/T = 0.5, t_p \le 10 \text{ ms}$ | I _{CM} | 100 | mA |
| Output power dissipation | | P _{diss} | 150 | mW |
| COUPLER | | | | |
| Isolation test voltage between emitter and detector, refer to climate DIN 40046, part 2, Nov. 74 | | V _{ISO} | 5000 | V_{RMS} |
| Isolation resistance | V _{IO} = 500 V, T _{amb} = 25 °C | R _{IO} | ≥ 10 ¹² | Ω |
| isolation resistance | V _{IO} = 500 V, T _{amb} = 100 °C | R _{IO} | ≥ 10 ¹¹ | Ω |
| Storage temperature range | | T _{stg} | -55 to +150 | °C |
| Ambient temperature range | | T _{amb} | -55 to +110 | °C |
| Soldering temperature (1) | 2 mm from case, ≤ 10 s | T _{sld} | 260 | °C |

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
 implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
 maximum ratings for extended periods of the time can adversely affect reliability
- (1) Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP)

| ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified) | | | | | | | | |
|--|---|------------|--------------------|------------------------|------|------|------|--|
| PARAMETER | TEST CONDITION | PART | SYMBOL | MIN. | TYP. | MAX. | UNIT | |
| INPUT | | | | | | | | |
| Forward voltage | $I_F = 60 \text{ mA}$ | | V_{F} | ı | 1.35 | 1.65 | V | |
| Reverse current | V _R = 6.0 V | | I _R | - | 0.01 | 10 | μΑ | |
| Capacitance | $V_R = 0 V, f = 1.0 MHz$ | | Co | - | 13 | - | pF | |
| OUTPUT | | | | | | | | |
| Collector emitter capacitance | $V_{CE} = 5.0 \text{ V}, f = 1.0 \text{ MHz}$ | | C _{CE} | ı | 5.2 | - | pF | |
| | V _{CF} = 10 V | SFH1617A-1 | I _{CEO} | ı | 2.0 | 50 | nA | |
| Collector emitter leakage | | SFH1617A-2 | I _{CEO} | - | 2.0 | 50 | nA | |
| current | v _{CE} = 10 v | SFH1617A-3 | I _{CEO} | I _{CEO} - 5.0 | 100 | nA | | |
| | | SFH1617A-4 | I _{CEO} | - | 5.0 | 100 | nA | |
| COUPLER | | | | | | | | |
| Collector emitter saturation voltage | I _F = 10 mA, f = 1.0 MHz | | V _{CEsat} | - | 0.25 | 0.4 | V | |
| Coupling capacitance | | | C_{C} | - | 0.4 | - | pF | |

Note

 Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements

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| CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified) | | | | | | | | |
|---|---|------------|----------|------|------|------|------|--|
| PARAMETER | TEST CONDITION | PART | SYMBOL | MIN. | TYP. | MAX. | UNIT | |
| | | SFH1617A-1 | CTR | 40 | - | 80 | % | |
| | I _E = 10 mA, V _{CE} = 5.0 V | SFH1617A-2 | CTR 63 - | - | 125 | % | | |
| | IF = 10 IIIA, VCE = 3.0 V | SFH1617A-3 | CTR | 100 | - | 200 | % | |
| 1 // | | SFH1617A-4 | CTR | 160 | - | 320 | % | |
| I _C /I _F | | SFH1617A-1 | CTR | 13 | 30 | - | % | |
| | $I_F = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$ | SFH1617A-2 | CTR | 22 | 45 | - | % | |
| | | SFH1617A-3 | CTR | 34 | 70 | - | % | |
| | | SFH1617A-4 | CTR | 56 | 90 | - | % | |

| PARAMETER | TEST CONDITION | PART | SYMBOL | MIN. | TYP. | MAX. | UNIT |
|-------------------|--|------------|------------------|------|------|------|------|
| NON-SATURATED | · | | | | | | |
| Turn-on time | $I_F = 10 \text{ mA}, V_{CC} = 5.0 \text{ V}, R_L = 75 \Omega$ | | t _{on} | - | 3.0 | - | μs |
| Rise time | $I_F = 10 \text{ mA}, V_{CC} = 5.0 \text{ V}, R_L = 75 \Omega$ | | t _r | = | 2.0 | = | μs |
| Turn-off time | $I_F = 10 \text{ mA}, V_{CC} = 5.0 \text{ V}, R_L = 75 \Omega$ | | t _{off} | - | 2.3 | - | μs |
| Fall time | $I_F = 10 \text{ mA}, V_{CC} = 5.0 \text{ V}, R_L = 75 \Omega$ | | t _f | - | 2.0 | - | μs |
| Cut-off frequency | I _F = 10 mA, V _{CC} = 5.0 V | | f _{ctr} | - | 100 | - | kHz |
| SATURATED | · | | | | | | |
| | I _F = 20 mA | SFH1617A-1 | t _{on} | - | 3.0 | - | μs |
| T time. | I _F = 10 mA | SFH1617A-2 | t _{on} | - | 4.2 | - | μs |
| Turn-on time | | SFH1617A-3 | t _{on} | - | 4.2 | - | μs |
| | I _F = 5.0 mA | SFH1617A-4 | t _{on} | - | 6.0 | - | μs |
| | I _F = 20 mA | SFH1617A-1 | t _r | - | 2.0 | - | μs |
| Dia a tima | I _F = 10 mA | SFH1617A-2 | t _r | - | 3.0 | - | μs |
| Rise time | | SFH1617A-3 | t _r | - | 3.0 | - | μs |
| | I _F = 5.0 mA | SFH1617A-4 | t _r | = | 4.6 | = | μs |
| | I _F = 20 mA | SFH1617A-1 | t _{off} | - | 18 | - | μs |
| | | SFH1617A-2 | t _{off} | - | 23 | - | μs |
| Turn-off time | I _F = 10 mA | SFH1617A-3 | t _{off} | - | 23 | - | μs |
| | I _F = 5.0 mA | SFH1617A-4 | t _{off} | - | 25 | - | μs |
| F. W. C. | I _F = 20 mA | SFH1617A-1 | t _f | - | 11 | - | μs |
| | I _F = 10 mA | SFH1617A-2 | t _f | - | 14 | - | μs |
| Fall time | | SFH1617A-3 | t _f | - | 14 | - | μs |
| | I _F = 5.0 mA | SFH1617A-4 | t _f | - | 15 | - | μs |

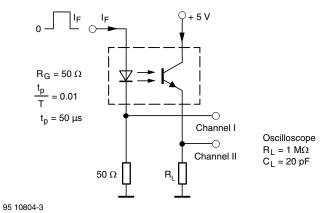


Fig. 1 - Test Circuit, Non-Saturated Operation

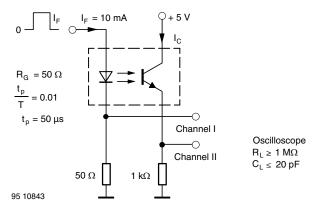


Fig. 2 - Test Circuit, Saturated Operation

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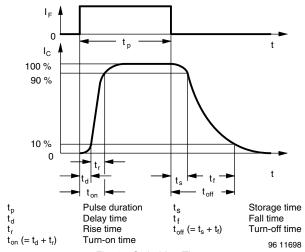


Fig. 3 - Switching Times

| SAFETY AND INSULATION RATINGS | | | | | | | | |
|-------------------------------|----------------------------|-------------------|------|---------------|------|------|--|--|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT | | |
| Climatic classification | According to IEC 68 part 1 | | - | 55 / 110 / 21 | = | | | |
| Comparative tracking index | | CTI | 175 | - | 399 | | | |
| Rated impulse voltage | | V _{IOTM} | - | - | 8 | kV | | |
| Maximum working voltages | Recurring peak voltage | V _{IORM} | - | - | 890 | V | | |
| Forward current | | I _{SI} | - | - | 275 | mA | | |
| Power dissipation | | Pso | - | - | 400 | mW | | |
| Safety temperature | | T _{SI} | - | - | 175 | °C | | |
| Creepage distance | | | 7.0 | - | - | mm | | |
| Clearance distance | | | 7.0 | - | = | mm | | |
| Isolation distance | per IEC 60950 2.10.5.1 | | 0.4 | - | - | mm | | |

Note

According to DIN EN 60747-5-2 (VDE 0884). These optocouplers are suitable for "safe electrical insulation" only within the safety ratings.
 Compliance with the safety ratings shall be ensured by means of protective circuits

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TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

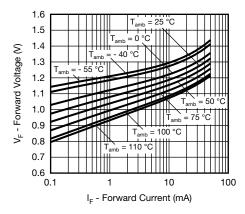


Fig. 4 - Forward Voltage vs. Forward Current

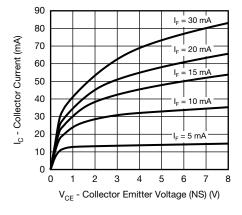


Fig. 5 - Collector Current vs. Collector Emitter Voltage (NS)

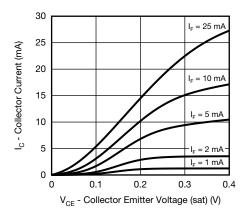


Fig. 6 - Collector Current vs. Collector Emitter Voltage (sat)

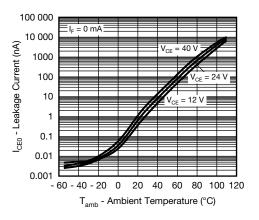


Fig. 7 - Leakage Current vs. Ambient Temperature

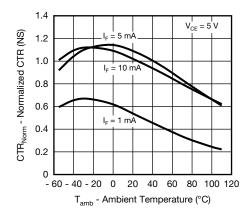


Fig. 8 - Normalized CTR (NS) vs. Ambient Temperature

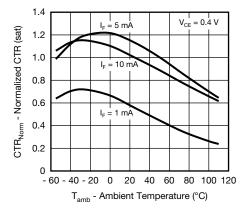


Fig. 9 - Normalized CTR (sat) vs. Ambient Temperature



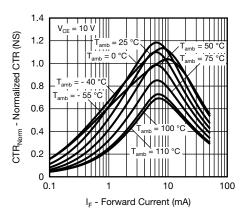


Fig. 10 - Normalized CTR (NS) vs. Forward Current

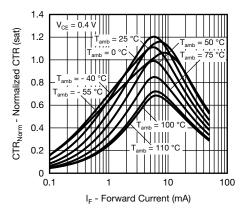


Fig. 11 - Normalized CTR (sat) vs. Forward Current

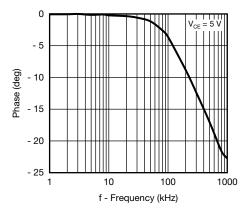


Fig. 12 - CTR Frequency vs. Phase Angle

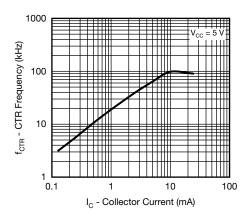


Fig. 13 - CTR Frequency vs. Collector Current

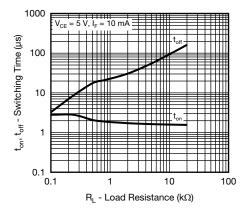
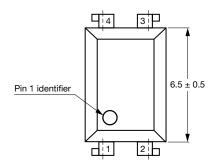


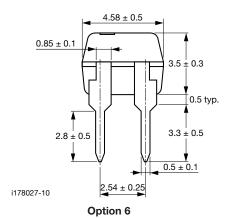
Fig. 14 - Switching Time vs. Load Resistance

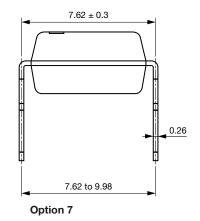


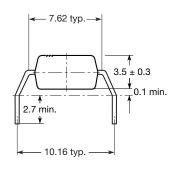
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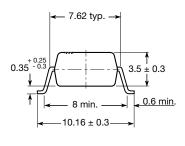
PACKAGE DIMENISONS in millimeters

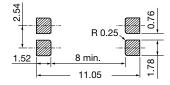












20802-30

PACKAGE MARKING



Notes

- VDE logo is only marked on option 1 parts. Option information is not marked on the part
- Tape and reel suffix (T) is not part of the package marking

Legal Disclaimer Notice



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